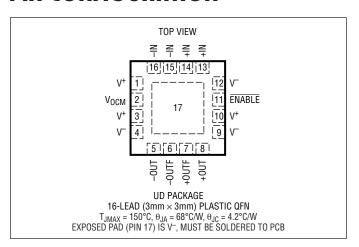
ABSOLUTE MAXIMUM RATINGS

(Note 1)

Supply Voltage (V _{CC} – V _{EE})	3.6V
Input Current (Note 2)	±10mA
Operating Temperature Range	
(Note 3)	40°C to 85°C
Specified Temperature Range	
(Note 4)	40°C to 85°C
Storage Temperature Range	–65°C to 150°C
Maximum Junction Temperature	150°C

PIN CONFIGURATION



ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE
LTC6401CUD-8#PBF	LTC6401CUD-8#TRPBF	LCCY	16-Lead (3mm × 3mm) Plastic QFN	0°C to 70°C
LTC6401IUD-8#PBF	LTC6401IUD-8#TRPBF	LCCY	16-Lead (3mm × 3mm) Plastic QFN	-40°C to 85°C

Consult LTC Marketing for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container. Consult LTC Marketing for information on non-standard lead based finish parts.

For more information on lead free part marking, go to: http://www.linear.com/leadfree/

For more information on tape and reel specifications, go to: http://www.linear.com/tapeandreel/

LTC6400 AND LTC6401 SELECTOR GUIDE Please check each datasheet for complete details.

PART NUMBER	GAIN (dB)	GAIN (V/V)	Z_IN (DIFFERENTIAL) (Ω)	I _{CC} (mA)
LTC6401-8	8	2.5	400	45
LTC6401-20	20	10	200	50
LTC6401-26	26	20	50	45
LTC6400-20	20	10	200	90
LTC6400-26	26	20	50	85

In addition to the LTC6401 family of amplifiers, a lower distortion LTC6400 family is available. The LTC6400 is pin compatible to the LTC6401, and has the same low noise performance. The LTC6400 shows higher linearity especially at input frequency above 140MHz at the expense of higher supply current. Please refer to the separate LTC6400 data sheets for complete details. Other gain versions from 8dB to 14dB will follow.



DC ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which <u>apply over</u> the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. $V^+ = 3V$, $V^- = 0V$, $+IN = -IN = V_{OCM} = 1.25V$, <u>ENABLE</u> = 0V, No R_L unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Input/Output C	haracteristic						
G _{DIFF}	Gain	V _{IN} = ±400mV Differential	•	7.5	8	8.5	dB
TC _{GAIN}	Gain Temperature Drift	V _{IN} = ±400mV Differential	•		-0.5		mdB/°C
V _{SWINGMIN}	Output Swing Low	Each Output, V _{IN} = ±1.6V Differential	•		89	170	mV
V _{SWINGMAX}	Output Swing High	Each Output, V _{IN} = ±1.6V Differential	•	2.3	2.42		V
V _{OUTDIFFMAX}	Maximum Differential Output Swing	1dB Compressed	•		4.6		V _{P-P}
I _{OUT}	Output Current Drive	V _{OUT} > 2V _{P-P,DIFF}	•	10			mA
V _{OS}	Input Offset Voltage	Differential	•	-4		4	mV
TCV _{OS}	Input Offset Voltage Drift	Differential	•		3		μV/°C
I _{VRMIN}	Input Common Mode Voltage Range, MIN					1	V
I _{VRMAX}	Input Common Mode Voltage Range, MAX			1.6			V
R _{INDIFF}	Input Resistance (+IN, -IN)	Differential	•	340	400	460	Ω
C _{INDIFF}	Input Capacitance (+IN, -IN)	Differential, Includes Parasitic			1		pF
R _{OUTDIFF}	Output Resistance (+OUT, -OUT)	Differential	•	18	25	32	Ω
R _{OUTFDIFF}	Filtered Output Resistance (+OUTF, -OUTF)	Differential	•	85	100	115	Ω
Coutfdiff	Filtered Output Capacitance (+OUTF, -OUTF)	Differential, Includes Parasitic			2.7		pF
CMRR	Common Mode Rejection Ratio	Input Common Mode Voltage 1.1V~1.4V	•	36	55		dB
Output Commo	on Mode Voltage Control						
G _{CM}	Common Mode Gain	V _{OCM} = 1V to 1.6V			1		V/V
V _{OCMMIN}	Output Common Mode Range, MIN		•			1 1.1	V
V _{OCMMAX}	Output Common Mode Range, MAX		•	1.6 1.5			V
V _{OSCM}	Common Mode Offset Voltage	V _{OCM} = 1.1V to 1.5V	•	-15		15	mV
TCV _{OSCM}	Common Mode Offset Voltage Drift		•		5		μV/°C
IV _{OCM}	V _{OCM} Input Current		•		3.6	15	μА
ENABLE Pin		1					
$\overline{V_{IL}}$	ENABLE Input Low Voltage		•			0.8	V
$\overline{V_{IH}}$	ENABLE Input High Voltage		•	2.4			V
I _{IL}	ENABLE Input Low Current	ENABLE = 0.8V	•			0.5	μА
I _{IH}	ENABLE Input High Current	ENABLE = 2.4V	•		1.4	4	μА
Power Supply		1					
$\overline{V_S}$	Operating Supply Range		•	2.85	3	3.5	V
Is	Supply Current	ENABLE = 0.8V, Input and Output Floating	•	36	45	60	mA
I _{SHDN}	Shutdown Supply Current	ENABLE = 2.4V, Input and Output Floating	•		0.8	3	mA
PSRR	Power Supply Rejection Ratio (Differential Outputs)	V+ = 2.85V to 3.5V	•	50	73.5		dB

AC ELECTRICAL CHARACTERISTICS Specifications are at T_A = 2

Specifications are at $T_A=25^{\circ}C.\ V^{+}=3V,\ V^{-}=0V,\ V_{0CM}=1.25V,$

ENABLE = 0	V. No R	unless	otherwise	noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
-3dBBW	-3dB Bandwidth	200mV _{P-P,OUT} (Note 6)	1	2.22		GHz
0.5dBBW	Bandwidth for 0.5dB Flatness	200mV _{P-P,OUT} (Note 6)		0.43		GHz
0.1dBBW	Bandwidth for 0.1dB Flatness	200mV _{P-P,OUT} (Note 6)		0.22		GHz
1/f	1/f Noise Corner			12.2		kHz
SR	Slew Rate	V _{OUT} = 2V Step (Note 6)		3400		V/µs
t _{S1%}	1% Settling Time	V _{OUT} = 2V _{P-P} (Note 6)		2.3		ns
t _{OVDR}	Overdrive Recovery Time	V _{OUT} = 1.9V _{P-P} (Note 6)		18		ns
t _{ON}	Turn-On Time	V _{OUT} Within 10% of Final Values		79		ns
t _{OFF}	Turn-Off Time	I _{CC} Falls to 10% of Nominal		193		ns
-3dBBW _{VOCM}	V _{OCM} Pin Small Signal –3dB BW	0.1V _{P-P} at V _{OCM} , Measured Single-Ended at Output (Note 6)		14		MHz
10MHz Input Signal						
HD2,10M/HD3,10M	Second/Third Order Harmonic Distortion	$V_{OUT} = 2V_{P-P}, R_L = 200\Omega$		-109/-88		dBc
		V _{OUT} = 2V _{P-P} , No R _L	-	-118/-100		dBc
IMD3,10M	Third-Order Intermodulation	$V_{OUT} = 2V_{P-P}$ Composite, $R_L = 200\Omega$		-88		dBc
	(f1 = 9.5MHz f2 = 10.5MHz)	V _{OUT} = 2V _{P-P} Composite, No R _L		-93		dBc
0IP3,10M	Equivalent Third-Order Output Intercept Point (f1 = 9.5MHz f2 = 10.5MHz)	V _{OUT} = 2V _{P-P} Composite, No R _L (Note 7)		50.7		dBm
P1dB,10M	1dB Compression Point	$R_L = 375\Omega$ (Notes 5, 7)		17.8		dBm
NF10M	Noise Figure	$R_L = 375\Omega$ (Note 5)		12.1		dB
e _{IN,10M}	Input Referred Voltage Noise Density	Includes Resistors (Short Inputs)		3.2		nV/√Hz
e _{ON,10M}	Output Referred Voltage Noise Density	Includes Resistors (Short Inputs)		8		nV/√Hz
70MHz Input Signal						
HD2,70M/HD3,70M	Second/Third Order Harmonic Distortion	$V_{OUT} = 2V_{P-P}, R_L = 200\Omega$		-91/-72		dBc
		V _{OUT} = 2V _{P-P} , No R _L		-100/-87		dBc
IMD3,70M	Third-Order Intermodulation	$V_{OUT} = 2V_{P-P}$ Composite, $R_L = 200\Omega$		-83		dBc
	(f1 = 69.5MHz f2 = 70.5MHz)	V _{OUT} = 2V _{P-P} Composite, No R _L		-92		dBc
0IP3,70M	Equivalent Third-Order Output Intercept Point (f1 = 69.5MHz f2 = 70.5MHz)	V _{OUT} = 2V _{P-P} Composite, No R _L (Note 7)		50		dBm
P1dB,70M	1dB Compression Point	$R_L = 375\Omega$ (Notes 5, 7)		18.3		dBm
NF70M	Noise Figure	$R_L = 375\Omega$ (Note 5)		12.2		dB
e _{IN,70M}	Input Referred Voltage Noise Density	Includes Resistors (Short Inputs)		3.2		nV/√Hz
e _{ON,70M}	Output Referred Voltage Noise Density	Includes Resistors (Short Inputs)		7.9		nV/√Hz

AC ELECTRICAL CHARACTERISTICS

Specifications are at $T_A = 25$ °C. $V^+ = 3V$, $V^- = 0V$, $V_{OCM} = 1.25V$,

 $\overline{\text{ENABLE}} = \text{OV}$, No R_L unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN TYP	MAX	UNITS
140MHz Input Signa	al				
HD2,140M/	Second/Third Order Harmonic Distortion	$V_{OUT} = 2V_{P-P}, R_L = 200\Omega$	-78/-59		dBc
HD3,140M		V _{OUT} = 2V _{P-P} , No R _L	-87/-70		dBc
IMD3,140M	Third-Order Intermodulation	$V_{OUT} = 2V_{P-P}$ Composite, $R_L = 200\Omega$	-71		dBc
	(f1 = 139.5MHz f2 = 140.5MHz)	$V_{OUT} = 2V_{P-P}$ Composite, No R _L	-80		dBc
OIP3,140M	Equivalent Third-Order Output Intercept Point (f1 = 139.5MHz f2 = 140.5MHz)	V _{OUT} = 2V _{P-P} Composite, No R _L (Note 7)	44.2		dBm
P1dB,140M	1dB Compression Point	$R_L = 375\Omega$ (Notes 5, 7)	18.7		dBm
NF140M	Noise Figure	$R_L = 375\Omega$ (Note 5)	12.3		dB
e _{IN,140M}	Input Referred Voltage Noise Density	Includes Resistors (Short Inputs)	3.1		nV/√Hz
e _{ON,140M}	Output Referred Voltage Noise Density	Includes Resistors (Short Inputs)	7.9		nV/√Hz
IMD3,130M/150M	Third-Order Intermodulation (f1 = 130MHz f2 = 150MHz) Measure at 170MHz	$V_{OUT} = 2V_{P-P}$ Composite, $R_L = 375\Omega$	-75	-67	dBc

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: Input pins (+IN, -IN) are protected by steering diodes to either supply. If the inputs go beyond either supply rail, the input current should be limited to less than 10mA.

Note 3: The LTC6401C and LTC6401I are guaranteed functional over the operating temperature range of –40°C to 85°C.

Note 4: The LTC6401C is guaranteed to meet specified performance from 0°C to 70°C. It is designed, characterized and expected to meet specified

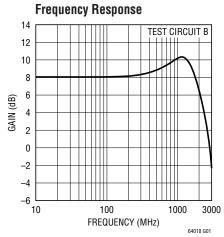
performance from -40° C to 85° C but is not tested or QA sampled at these temperatures. The LTC6401I is guaranteed to meet specified performance from -40° C to 85° C.

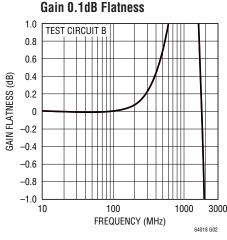
Note 5: Input and output baluns used. See Test Circuit A.

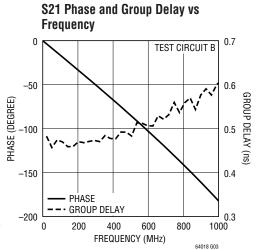
Note 6: Measured using Test Circuit B. $R_L = 87.5\Omega$ per output.

Note 7: Since the LTC6401-8 is a feedback amplifier with low output impedance, a resistive load is not required when driving an AD converter. Therefore, typical output power is very small. In order to compare the LTC6401-8 with amplifiers that require 50Ω output load, the LTC6401-8 output voltage swing driving a given R_L is converted to OIP3 and P_{1dB} as if it were driving a 50Ω load. Using this modified convention, $2V_{P-P}$ is by definition equal to 10dBm, regardless of actual R_L .

TYPICAL PERFORMANCE CHARACTERISTICS

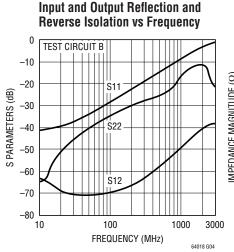


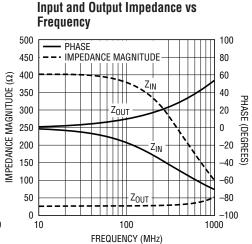


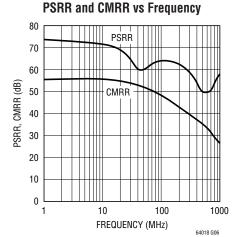


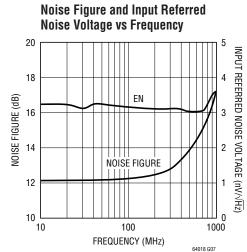
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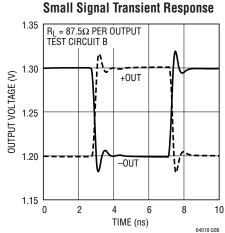
TYPICAL PERFORMANCE CHARACTERISTICS

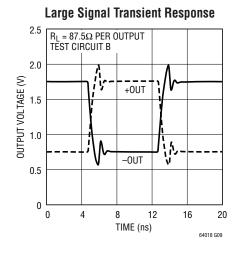


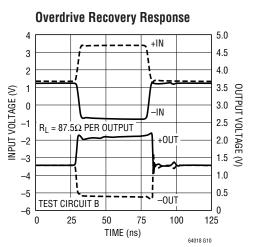


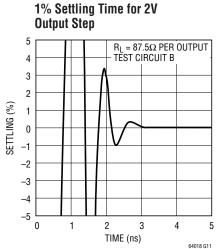


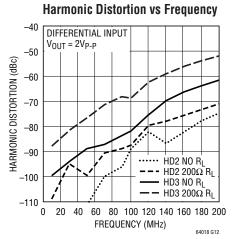












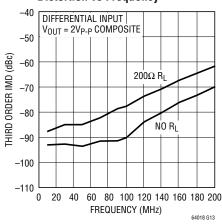
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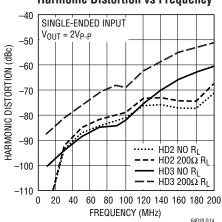


TYPICAL PERFORMANCE CHARACTERISTICS

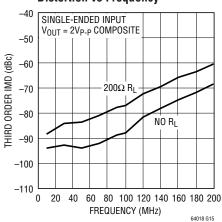
Third Order Intermodulation Distortion vs Frequency



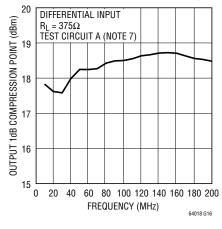
Harmonic Distortion vs Frequency



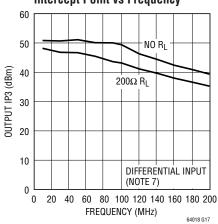
Third Order Intermodulation Distortion vs Frequency



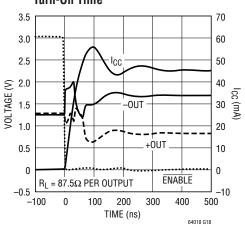
Equivalent Output 1dB Compression Point vs Frequency



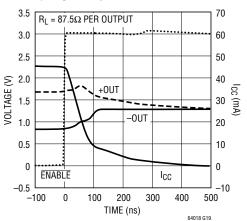
Equivalent Output Third Order Intercept Point vs Frequency



Turn-On Time



Turn-Off Time



PIN FUNCTIONS

V⁺ (**Pins 1, 3, 10**): Positive Power Supply (Normally tied to 3V or 3.3V). All three pins must be tied to the same voltage. Bypass each pin with 1000pF and $0.1\mu F$ capacitors as close to the pins as possible.

 V_{OCM} (Pin 2): This pin sets the output common mode voltage. A 0.1µF external bypass capacitor is recommended.

V⁻ (**Pins 4, 9, 12, 17**): Negative Power Supply. All four pins must be connected to same voltage/ground.

-OUT, +OUT (Pins 5, 8): Unfiltered Outputs. These pins have series resistors, R_{OUT} 12.5 Ω .

-OUTF, **+OUTF** (**Pins 6**, **7**): Filtered Outputs. These pins have 50Ω series resistors and a 2.7pF shunt capacitor.

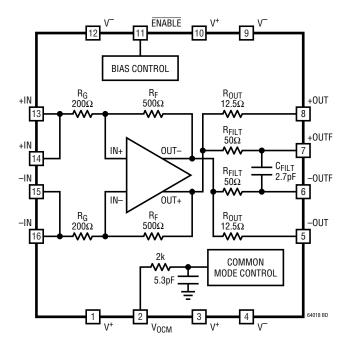
ENABLE (Pin 11): This pin is a logic input referenced to V_{EE} . If low, the part is enabled. If high, the part is disabled and draws very low standby current while the internal op amp has high output impedance.

+IN (Pins 13, 14): Positive Input. Pins 13 and 14 are internally shorted together.

-IN (Pins 15, 16): Negative Input. Pins 15 and 16 are internally shorted together.

Exposed Pad (Pin 17): V⁻. The Exposed Pad must be connected to same voltage/ground as pins 4, 9, 12.

BLOCK DIAGRAM





Circuit Operation

The LTC6401-8 is a low noise and low distortion fully differential op amp/ADC driver with:

- Operation from DC to 2.2GHz -3dB bandwidth
- Fixed gain of 2.5V/V (8dB)
- Differential input impedance 400Ω
- Differential output impedance 25Ω
- Differential impedance of output filter 100Ω

The LTC6401-8 is composed of a fully differential amplifier with on chip feedback and output common mode voltage control circuitry. Differential gain and input impedance are set by $200\Omega/500\Omega$ resistors in the feedback network. Small output resistors of 12.5Ω improve the circuit stability over various load conditions. They also provide a possible external filtering option, which is often desirable when the load is an ADC.

Filter resistors of 50Ω are available for additional filtering. Lowpass/bandpass filters are easily implemented with just a couple of external components. Moreover, they offer single-ended 50Ω matching in wideband applications and no external resistor is needed.

The LTC6401-8 is very flexible in terms of I/O coupling. It can be AC- or DC-coupled at the inputs, the outputs or both. Due to the internal connection between input and output, users are advised to keep input common mode voltage between 1V and 1.6V for proper operation. If the inputs are AC-coupled, the input common mode voltage is automatically biased approximately 250mV above $V_{\rm OCM}$ and thus no external circuitry is needed for bias. The LTC6401-8 provides an output common mode voltage set by $V_{\rm OCM}$, which allows driving ADC directly without external components such as transformer or AC coupling capacitors. The input signal can be either single-ended or differential with only minor difference in distortion performance.

Input Impedance and Matching

The differential input impedance of the LTC6401-8 is 400Ω . Usually the differential inputs need to be terminated to a lower value impedance, e.g. 50Ω , in order to provide an impedance match for the source. Several choices are available. One approach is to use a differential shunt resistor (Figure 1). Another approach is to employ a wideband transformer and shunt resistor (Figure 2). Both methods provide a wideband match. The termination resistor or the transformer must be placed close to the input pins in order to minimize the reflection due to input mismatch. Alternatively, one could apply a narrowband impedance match at the inputs of the LTC6401-8 for frequency selection and/or noise reduction.

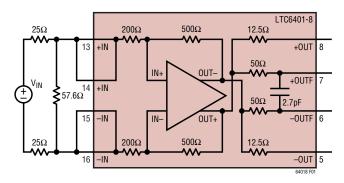


Figure 1. Input Termination for Differential 50 $\!\Omega$ Input Impedance Using Shunt Resistor

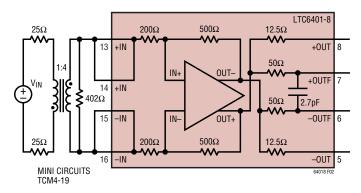


Figure 2. Input Termination for Differential 50 $\!\Omega$ Input Impedance Using a Balun



Referring to Figure 3, LTC6401-8 can be easily configured for single-ended input and differential output without a balun. The signal is fed to one of the inputs through a matching network while the other input is connected to the same matching network and a source resistor. Because the return ratios of the two feedback paths are equal, the two outputs have the same gain and thus symmetrical swing. In general, the single-ended input impedance and termination resistor R_T are determined by the combination of R_S , R_G and R_F For example, when R_S is 50Ω , it is found that the single-ended input impedance is 322Ω and R_T is 59Ω in order to match to a 50Ω source impedance.

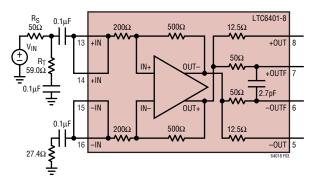


Figure 3. Input Termination for Single-Ended 50 $\!\Omega$ Input Impedance

The LTC6401-8 is unconditionally stable, i.e. differential stability factor Kf>1 and stability measure B1>0. However, the overall differential gain is affected by both source impedance and load impedance as shown in Figure 4:

$$A_V = \left| \frac{V_{OUT}}{V_{IN}} \right| = \frac{1000}{R_S + 400} \cdot \frac{R_L}{25 + R_L}$$

The noise performance of the LTC6401-8 also depends upon the source impedance and termination. For example, an input 1:4 transformer in Figure 2 improves SNR by adding 6dB gain at the inputs. A trade-off between gain

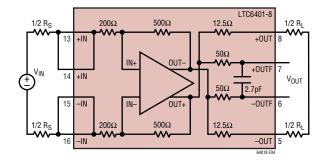


Figure 4. Calculate Differential Gain

and noise is obvious when constant noise figure circle and constant gain circle are plotted within the input Smith Chart, based on which users can choose the optimal source impedance for a given gain and noise requirement.

Output Impedance Match and Filter

The LTC6401-8 can drive an ADC directly without external output impedance matching. Alternatively, the differential output impedance of 25Ω can be made larger, e.g. 50Ω , by series resistors or LC network.

The internal low pass filter outputs at +OUTF/-OUTF have a -3dB bandwidth of 590MHz. External capacitors can reduce the lowpass filter bandwidth as shown in Figure 5. A bandpass filter is easily implemented with

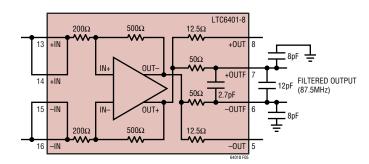


Figure 5. LTC6401-8 Internal Filter Topology Modified for Low Filter Bandwidth (Three External Capacitors)

LINEAR

only a few components as shown in Figure 6. Three 39pF capacitors and a 16nH inductor create a bandpass filter with 165MHz center frequency, –3dB frequencies at 138MHz and 200MHz.

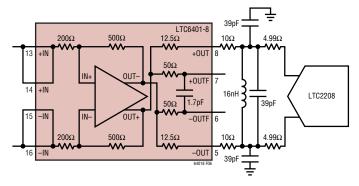


Figure 6. LTC6401-8 Modified 165MHz for Bandpass Filtering (Three External Capacitors, One External Inductor)

Output Common Mode Adjustment

The LTC6401-8's output common mode voltage is set by the V_{OCM} pin, which is a high impedance input. The output common mode voltage is capable of tracking V_{OCM} in a range from 1V to 1.6V. Bandwidth of V_{OCM} control is typically 14MHz, which is dominated by a low pass filter connected to the V_{OCM} pin and is aimed to reduce common mode noise generation at the outputs. The internal common mode feedback loop has a -3dB bandwidth around 400MHz, allowing fast rejection of any common mode output voltage disturbance. The V_{OCM} pin should be tied to a DC bias voltage with a $0.1\mu\text{F}$ bypass capacitor. When interfacing with 3V A/D converters such as the LT22xx families, the V_{OCM} pin can be connected to the V_{CM} pin of the ADC.

Driving A/D Converters

The LTC6401-8 has been specifically designed to interface directly with high speed A/D converters. Figure 7 shows the

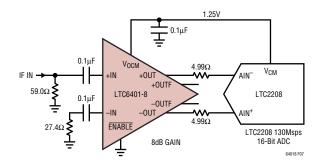


Figure 7. Single-Ended Input to LTC6401-8 and LTC2208

LTC6401-8 with single-ended input driving the LTC2208, which is a 16-bit, 130Msps ADC. Two external 5Ω resistors help eliminate potential resonance associated with bond wires of either the ADC input or the driver output. V_{OCM} of the LTC6401-8 is connected to V_{CM} of the LTC2208 at 1.25V. Alternatively, an input single-ended signal can be converted to differential signal via a balun and fed to the input of the LTC6401-8.

Figure 8 summarizes the IMD3 performance of the whole system as shown in Figure 7.

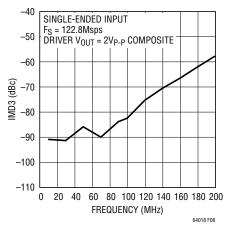


Figure 8. IMD3 for the Combination of LTC6401-8 and LTC2208

Test Circuits

Due to the fully-differential design of the LTC6401 and its usefulness in applications with differing characteristic specifications, two test circuits are used to generate the information in this datasheet. Test Circuit A is DC987B, a two-port demonstration circuit for the LTC6401 family. The silkscreen is shown in Figure 9. This circuit includes input and output transformers (baluns) for single-ended-to-differential conversion and impedance transformation, allowing direct hook-up to a 2-port network analyzer. There are also series resistors at the output to present the LTC6401 with a 375Ω differential load, optimizing distortion performance. Due to the input and output transformers, the -3dB bandwidth is reduced from 2.2GHz to approximately 1.65GHz.

Test Circuit B uses a 4-port network analyzer to measure S-parameters and gain/phase response. This removes the effects of the wideband baluns and associated circuitry, for a true picture of the >1GHz S-parameters and AC characteristics.

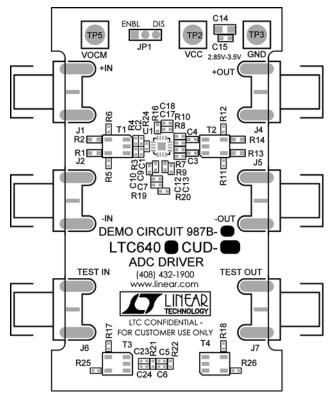
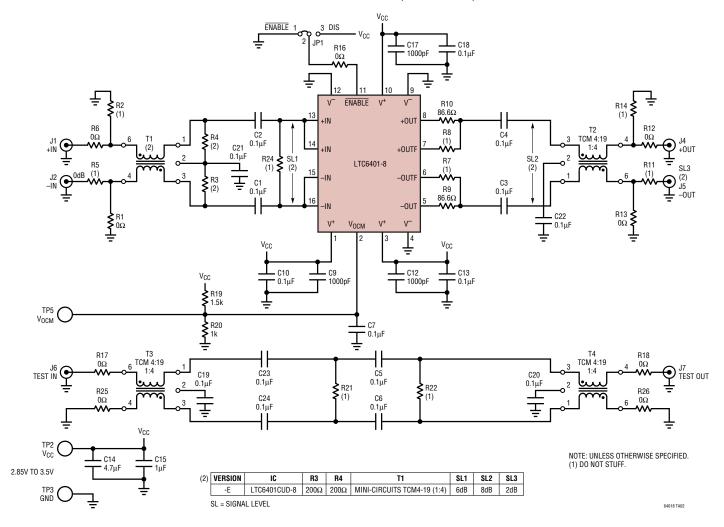


Figure 9. Top Silkscreen for DC987B. Test Circuit A

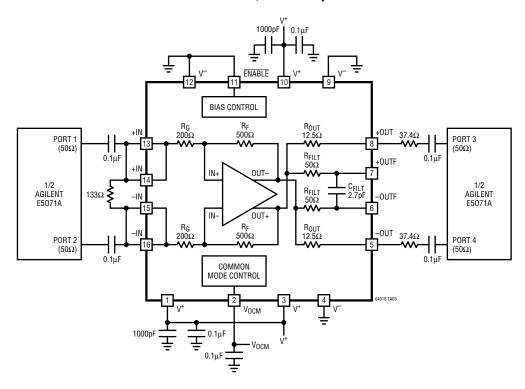
TYPICAL APPLICATIONS

Demo Circuit 987B Schematic (Test Circuit A)



TYPICAL APPLICATIONS

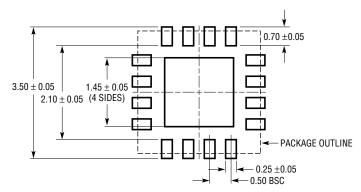
Test Circuit B, 4-Port Analysis



PACKAGE DESCRIPTION

UD Package 16-Lead Plastic QFN (3mm × 3mm)

(Reference LTC DWG # 05-08-1691)



RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS

BOTTOM VIEW—EXPOSED PAD PIN 1 NOTCH R = 0.20 TYP R = 0.115 0.75 ± 0.05 3.00 ± 0.10 OR $0.25 \times 45^{\circ}$ CHAMFER TYP (4 SIDES) 15 16 0.40 ± 0.10 TOP MARK (NOTE 6) 1.45 ± 0.10 (4-SIDES) - 0.200 REF -0.25 ± 0.05 → 0.00 - 0.05 0.50 BSC

NOTE:

- 1. DRAWING CONFORMS TO JEDEC PACKAGE OUTLINE MO-220 VARIATION (WEED-2)
- 2. DRAWING NOT TO SCALE
- 3. ALL DIMENSIONS ARE IN MILLIMETERS
- 4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
- EXPOSED PAD SHALL BE SOLDER PLATED
 SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION
 ON THE TOP AND BOTTOM OF PACKAGE



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
High-Speed Diffe	erential Amplifiers/Differential Op Amps	
LT®1993-2	800MHz Differential Amplifier/ADC Driver	A _V = 2V/V, OIP3 = 38dBm at 70MHz
LT1993-4	900MHz Differential Amplifier/ADC Driver	$A_V = 4V/V$, OIP3 = 40dBm at 70MHz
LT1993-10	700MHz Differential Amplifier/ADC Driver	A _V = 10V/V, OIP3 = 40dBm at 70MHz
LT1994	Low Noise, Low Distortion Differential Op Amp	16-Bit SNR and SFDR at 1MHz, Rail-to-Rail Outputs
LT5514	Ultralow Distortion IF Amplifier/ADC Driver with Digitally Controlled Gain	OIP3 = 47dBm at 100MHz, Gain Control Range 10.5dB to 33dB
LT5524	Low Distortion IF Amplifier/ADC Driver with Digitally Controlled Gain	OIP3 = 40dBm at 100MHz, Gain Control Range 4.5dB to 37dB
LTC6400-20	1.8GHz Low Noise, Low Distortion, Differential ADC Driver	A _V = 20dB, 90mA Supply Current, IMD3 = -65dBc at 300MHz
LTC6400-26	1.9GHz Low Noise, Low Distortion, Differential ADC Driver	A _V = 26dB, 85mA Supply Current, IMD3 = -71dBc at 300MHz
LTC6401-20	1.3GHz Low Noise, Low Distortion, Differential ADC Driver	A _V = 20dB, 50mA Supply Current, IMD3 = -74dBc at 140MHz
LTC6401-26	1.6GHz Low Noise, Low Distortion, Differential ADC Driver	A _V = 26dB, 45mA Supply Current, IMD3 = -72dBc at 140MHz
LT6402-6	300MHz Differential Amplifier/ADC Driver	A _V = 6dB, Distortion < -80dBc at 25MHz
LT6402-12	300MHz Differential Amplifier/ADC Driver	A _V = 12dB, Distortion < -80dBc at 25MHz
LT6402-20	300MHz Differential Amplifier/ADC Driver	A _V = 20dB, Distortion < -80dBc at 25MHz
LTC6404-1	600MHz Low Noise Differential ADC Driver	$e_n = 1.5 \text{nV}/\sqrt{\text{Hz}}$, Rail-to-Rail Outputs
LTC6406	3GHz Rail-to-Rail Input Differential Op Amp	1.6nV/√Hz Noise, −72dBc Distortion at 50MHz, 18mA
LT6411	Low Power Differential ADC Driver/Dual Selectable Gain Amplifier	16mA Supply Current, IMD3 = -83 dBc at 70MHz, $A_V = 1$, -1 or 2
High-Speed Sing	le-Ended Output Op Amps	
LT1812/LT1813/ LT1814	High Slew Rate Low Cost Single/Dual/Quad Op Amps	8nV/√Hz Noise, 750V/μs, 3mA Supply Current
LT1815/LT1816/ LT1817	Very High Slew Rate Low Cost Single/Dual/Quad Op Amps	6nV/√Hz Noise, 1500V/μs, 6.5mA Supply Current
LT1818/LT1819	Ultra High Slew Rate Low Cost Single/Dual Op Amps	6nV/√Hz Noise, 2500V/µs, 9mA Supply Current
LT6200/LT6201	Rail-to-Rail Input and Output Low Noise Single/Dual Op Amps	0.95nV/√Hz Noise, 165MHz GBW, Distortion = −80dBc at 1MHz
LT6202/LT6203/ LT6204	Rail-to-Rail Input and Output Low Noise Single/Dual/Quad Op Amps	1.9nV/√Hz Noise, 3mA Supply Current, 100MHz GBW
LT6230/LT6231/ LT6232	Rail-to-Rail Output Low Noise Single/Dual/Quad Op Amps	1.1nV/√Hz Noise, 3.5mA Supply Current, 215MHz GBW
LT6233/LT6234/ LT6235	Rail-to-Rail Output Low Noise Single/Dual/Quad Op Amps	1.9nV/√Hz Noise, 1.2mA Supply Current, 60MHz GBW
Integrated Filters	8	
LTC1562-2	Very Low Noise, 8th Order Filter Building Block	Lowpass and Bandpass Filters up to 300kHz
LT1568	Very Low Noise, 4th Order Filter Building Block	Lowpass and Bandpass Filters up to 10MHz
LTC1569-7	Linear Phase, Tunable 10th Order Lowpass Filter	Single-Resistor Programmable Cut-Off to 300kHz
LT6600-2.5	Very Low Noise Differential 2.5MHz Lowpass Filter	SNR = 86dB at 3V Supply, 4th Order Filter
LT6600-5	Very Low Noise Differential 5MHz Lowpass Filter	SNR = 82dB at 3V Supply, 4th Order Filter
LT6600-10	Very Low Noise Differential 10MHz Lowpass Filter	SNR = 82dB at 3V Supply, 4th Order Filter
LT6600-15	Very Low Noise Differential 15MHz Lowpass Filter	SNR = 76dB at 3V Supply, 4th Order Filter
LT6600-20	Very Low Noise Differential 20MHz Lowpass Filter	SNR = 76dB at 3V Supply, 4th Order Filter

